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Docket No.: TCP-004

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Confirmation No.

Kenji WATANABE et al

U.S. Patent Application No.: -----

Group Art Unit: -----

Filed: herewith

For:

A HIGHLY PURE HEXAGONAL BORON NITRIDE SINGLE CRYSTAL

CAPABLE OF EMITTING HIGH-LUMINANCE FAR ULTRAVIOLET LIGHT, A

METHOD FOR PRODUCING THE SAME, HIGH-LUMINANCE FAR

ULTRAVIOLET LIGHT EMITTING ELEMENT INLCUDING SAID SINGLE CRYSTAL, AND SOLID-STATE LASER AND SOLID STATE LIGHT EMITTING

APPARATUS UTILIZING THE ELEMENT

## INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed with the application and no certification or fee is required.

Please note this is a PCT application in the entry of the National Phase in the U.S. and copies of the references cited were transmitted by WIPO. Copies of the foreign search report and the references cited are attached for the Examiner's information. Acknowledgement and consideration of these documents are respectfully requested.

Respectfully submitted,

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Date: February 2, 2006

## INFORMATION DISCLOSURE CITATION IN AN APPLICATION

ATTY. DOCKET NO.
TCP-004

APPLICANT
Kenji WATANABE et al

FILING DATE

GROUP

(PTO-1449)			herewith				
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EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILI DA	
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EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Transla Yes	ltion No
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	gradient method	ander high pressur	re;" Journal of Crystal Grow	vth, 2001, vol	. 222, pages	549-557.	
			growth of cubic boron nitri , pages 1709-1713.	de using a Ca	a-B-N solven	t"; Diam	iond
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EXAMINER	L		DATE CONSIDER	ED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.